

SN54AHCT367, SN74AHCT367 HEX BUFFERS AND LINE DRIVERS WITH 3-STATE OUTPUTS

SCLS418F – JUNE 1998 – REVISED MAY 2002

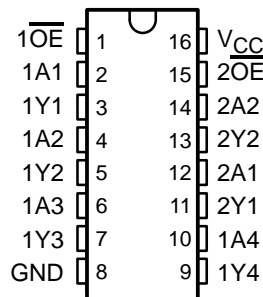
- Inputs Are TTL-Voltage Compatible
- True Outputs
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

description

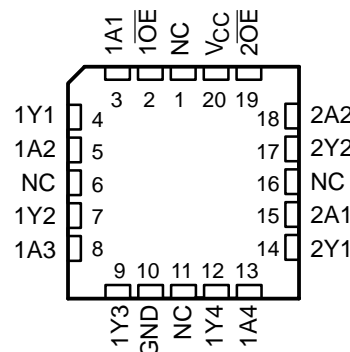
The 'AHCT367 devices are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. These devices are organized as dual 4-line and 2-line buffers/drivers with active-low output-enable ($\overline{1OE}$ and $\overline{2OE}$) inputs. When \overline{OE} is low, the device passes noninverted data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

SN54AHCT367 . . . J OR W PACKAGE
SN74AHCT367 . . . D, DB, DGV, N, NS, OR PW PACKAGE
(TOP VIEW)



SN54AHCT367 . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection

ORDERING INFORMATION

T_A	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	PDIP – N	Tube	SN74AHCT367N	SN74AHCT367N
	SOIC – D	Tube	SN74AHCT367D	AHCT367
		Tape and reel	SN74AHCT367DR	
	SOP – NS	Tape and reel	SN74AHCT367NSR	AHCT367
	SSOP – DB	Tape and reel	SN74AHCT367DBR	HB367
	TSSOP – PW	Tape and reel	SN74AHCT367PWR	HB367
–55°C to 125°C	TVSOP – DGV	Tape and reel	SN74AHCT367DGVR	HB367
	CDIP – J	Tube	SNJ54AHCT367J	SNJ54AHCT367J
	CFP – W	Tube	SNJ54AHCT367W	SNJ54AHCT367W
	LCCC – FK	Tube	SNJ54AHCT367FK	SNJ54AHCT367FK

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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**TEXAS
INSTRUMENTS**

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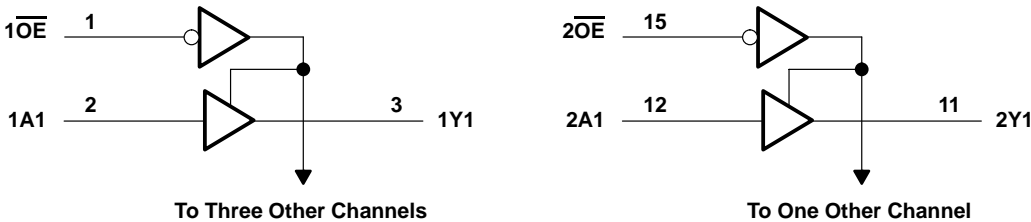
SN54AHCT367, SN74AHCT367
HEX BUFFERS AND LINE DRIVERS
WITH 3-STATE OUTPUTS

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FUNCTION TABLE
(each buffer/driver)

INPUTS		OUTPUT Y
\overline{OE}	A	
H	X	Z
L	H	H
L	L	L

logic diagram (positive logic)



Pin numbers shown are for the D, DB, DGV, J, N, NS, PW, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}	–0.5 V to 7 V
Input voltage range, V_I (see Note 1)	–0.5 V to 7 V
Output voltage range, V_O (see Note 1)	–0.5 V to $V_{CC} + 0.5$ V
Input clamp current, I_{IK} ($V_I < 0$)	–20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±25 mA
Continuous current through V_{CC} or GND	±75 mA
Package thermal impedance, θ_{JA} (see Note 2):	
D package	73°C/W
DB package	82°C/W
DGV package	120°C/W
N package	67°C/W
NS package	64°C/W
PW package	108°C/W
Storage temperature range, T_{stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The package thermal impedance is calculated in accordance with JESD 51-7.

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recommended operating conditions (see Note 3)

		SN54AHCT367		SN74AHCT367		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
V_I	Input voltage	0	5.5	0	5.5	V
V_O	Output voltage	0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current		–8		–8	mA
I_{OL}	Low-level output current		8		8	mA
$\Delta t/\Delta v$	Input transition rise or fall rate		20		20	ns/V
T_A	Operating free-air temperature	–55	125	–40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V_{CC}	$T_A = 25^\circ\text{C}$			SN54AHCT367		SN74AHCT367		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V_{OH}	$I_{OH} = -50\ \mu\text{A}$	4.5 V	4.4	4.5		4.4		4.4		V
	$I_{OH} = -8\ \text{mA}$		3.94			3.8		3.8		
V_{OL}	$I_{OL} = 50\ \mu\text{A}$	4.5 V			0.1	0.1		0.1		V
	$I_{OL} = 8\ \text{mA}$				0.36	0.44		0.44		
I_I	$V_I = 5.5\ \text{V}$ or GND	0 V to 5.5 V			$\pm 0.1^*$		$\pm 1^*$		± 1	μA
I_{OZ}	$V_I = V_{CC}$ or GND, $\overline{OE} = V_{IH}$	5.5 V			± 0.25		± 2.5		± 2.5	μA
I_{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μA
ΔI_{CC}^\dagger	One input at 3.4 V, Other inputs at V_{CC} or GND	5.5 V			1.35		1.5		1.5	mA
C_i	$V_I = V_{CC}$ or GND	5 V		2.5	10		10		10	pF
C_o	$V_O = V_{CC}$ or GND	5 V		5						pF

* On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0\ \text{V}$.

† This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC} .

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switching characteristics over recommended operating free-air temperature range,
 $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			SN54AHCT367		SN74AHCT367		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	Y	$C_L = 15\text{ pF}$	2.5*	4.8*		1*	6.5*	1	5.5	ns
t_{PHL}				2.5*	4.8*		1*	6.5*	1	5.5	
t_{PZH}	\overline{OE}	Y	$C_L = 15\text{ pF}$	3.5*	8*		1*	9.5*	1	8.5	ns
t_{PZL}				2.8*	7*		1*	8.5*	1	7.5	
t_{PHZ}	\overline{OE}	Y	$C_L = 15\text{ pF}$	3.1*	8*		1*	9.5*	1	8.5	ns
t_{PLZ}				2.8*	7*		1*	8.5*	1	7.5	
t_{PLH}	A	Y	$C_L = 50\text{ pF}$	3.5	5.8		1	7.5	1	6.5	ns
t_{PHL}				3.3	5.8		1	7.5	1	6.5	
t_{PZH}	\overline{OE}	Y	$C_L = 50\text{ pF}$	4.5	9		1	10.5	1	9.5	ns
t_{PZL}				3.7	8		1	9.5	1	8.5	
t_{PHZ}	OE	Y	$C_L = 50\text{ pF}$	4.1	9		1	10.5	1	9.5	ns
t_{PLZ}				3.6	8		1	9.5	1	8.5	

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, $V_{CC} = 5\text{ V}$, $C_L = 50\text{ pF}$, $T_A = 25^\circ\text{C}$ (see Note 4)

PARAMETER		SN74AHCT367			UNIT
		MIN	TYP	MAX	
$V_{OL(P)}$	Quiet output, maximum dynamic V_{OL}		0.4		V
$V_{OL(V)}$	Quiet output, minimum dynamic V_{OL}		–0.4		V
$V_{OH(V)}$	Quiet output, minimum dynamic V_{OH}		4.7		V
$V_{IH(D)}$	High-level dynamic input voltage	2			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.8	V

NOTE 4: Characteristics are for surface-mount packages only.

operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

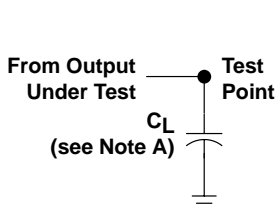
PARAMETER	TEST CONDITIONS	TYP	UNIT
C_{pd} Power dissipation capacitance	No load, $f = 1\text{ MHz}$	22	pF

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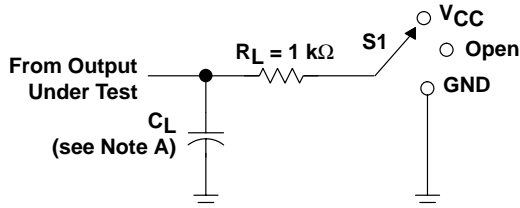


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PARAMETER MEASUREMENT INFORMATION

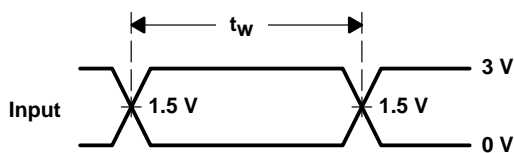


LOAD CIRCUIT FOR
TOTEM-POLE OUTPUTS

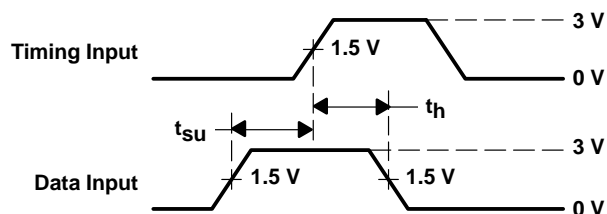


LOAD CIRCUIT FOR
3-STATE AND OPEN-DRAIN OUTPUTS

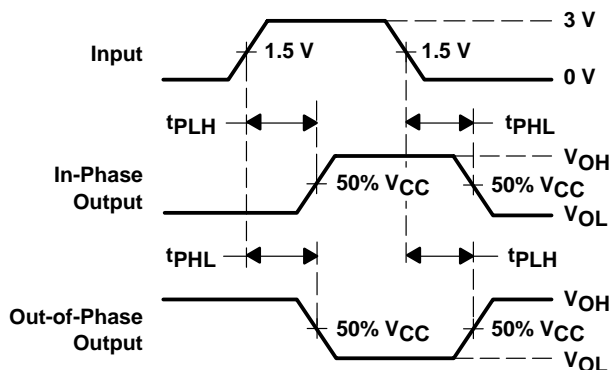
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{CC}
t_{PHZ}/t_{PZH}	GND
Open Drain	V_{CC}



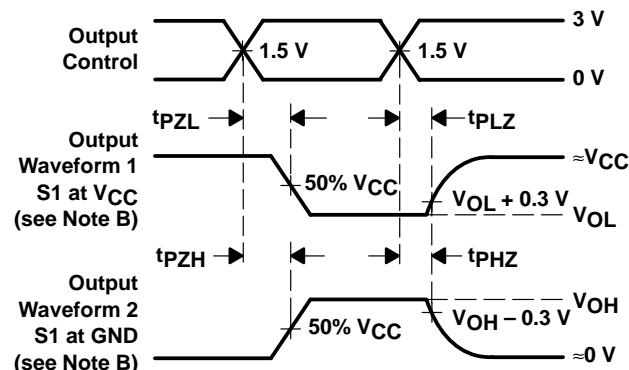
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

- NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 3 \text{ ns}$, $t_f \leq 3 \text{ ns}$.
D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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